

The G8195 series are high-speed receivers specifically developed for 1.3/1.55 µm band power monitor in optical fiber communications. These devices incorporate a high-speed, high-sensitivity InGaAs PIN photodiode integrated in a pigtail module.

Features

Applications

Power monitor in optical fiber communications

- High-speed response: 2 GHz typ.
- Low dark current: 20 pA typ.
- High sensitivity: 0.9 A/W typ. (λ=1.31 μm)
- Low capacitance: 1 pF typ.

Absolute maximum ratings (Ta=25 °C)

Parameter	Symbol	Value	Unit
Reverse voltage	VR max	20	V
Operating temperature	Topr	-20 to +70	°C
Storage temperature	Tstg	-40 to +85	°C

Electrical and optical characteristics (Ta=25 °C)

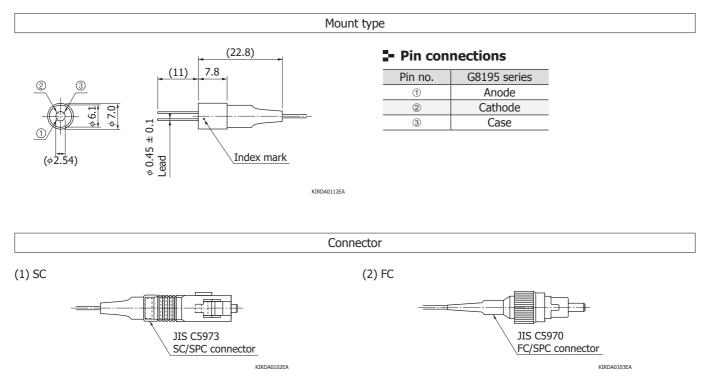
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Spectral response range	λ		-	0.9 to 1.7	-	μm
Peak sensitivity wavelength	λр		-	1.55	-	μm
Photo sensitivity	S*	λ=1.3 μm	0.75	0.9	-	A/W
		λ=1.55 μm	0.8	0.95	-	A/W
Dark current	ID	VR=5 V	-	0.02	0.4	nA
Cutoff frequency	fc	VR=5 V, RL=50 Ω λ=1.3 μm, -3 dB	-	2	-	GHz
Terminal capacitance	Ct	VR=5 V, f=1 MHz	-	1	1.5	pF
Noise equivalent power	NEP	VR=5 V, λ=1.55 μm	-	3 × 10 ⁻¹⁵	-	W/Hz ^{1/2}

* Using a single mode opticul fiber with a master plug

Package lineup

Configuration	G8195-11	G8195-12			
Mount type	Coaxial				
Fiber	SM (9.5/125) ϕ 0.9 mm, 1 m +20 cm/-0 cm				
Connector	SC	FC			

Dimensional outline (unit: mm, tolerance unless otherwise noted: ±0.2)



Information described in this material is current as of November, 2011.

Product specifications are subject to change without prior notice due to improvements or other reasons. Before assembly into final products, please contact us for the delivery specification sheet to check the latest information.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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